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71 Applicant: **Post Office, 23 Howland Street, London W1P 6HQ (GB)**

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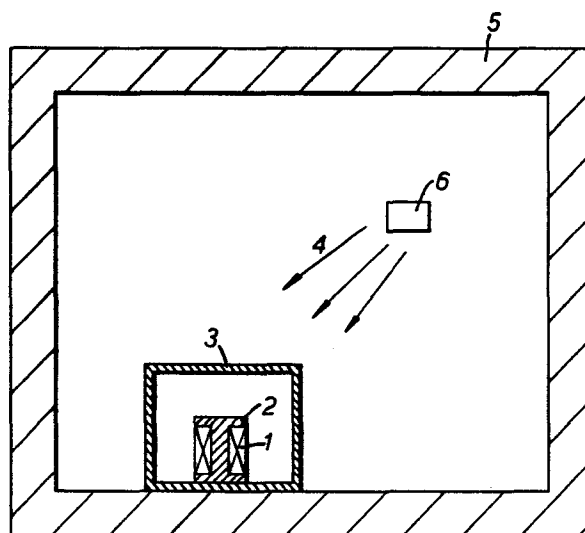
72 Inventor: **Pantelis, Philippos, 6 Hazelcroft Road, Ipswich Suffolk (GB)**

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74 Representative: **Pike, Harold John et al, Abel & Imray Northumberland House 303-306 High Holborn, London, WC1V 7LH (GB)**

54 Improvements in or relating to piezoelectric materials and to methods for producing such materials.

57 The piezoelectric properties of a polymeric material, for example polyvinylidene may be enhanced by «poling», which usually involves the application to the material, whilst at an elevated temperature, of a high voltage electric field. The enhancement is however limited by the temperature and electric field that the material can tolerate. Further enhancement is obtained by exposing the material (1) to a quantity of γ radiation (4) of between 1 and 200 Mrads before «poling»; best results are obtained at an exposure level of between 1 and 100 Mrads. The treated material is suitable for use in microphone transmitters, receivers and pressure transducers.



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Improvements in or relating to piezoelectric materials
and to methods for producing such materials.

This invention relates to piezoelectric materials and to methods for producing such materials. The invention has particular reference to polymeric materials exhibiting piezoelectric properties and to
5 the production of such materials for use in electro-acoustic transducer devices.

It has been found that certain polymeric materials, for example polyvinylidene fluoride (hereinafter referred to as PVF_2), exhibit piezoelectric
10 properties, and that these properties can be enhanced considerably by exposing the material to treatment known as "poling". Poling usually involves the application to the material, whilst at an elevated temperature, of a high voltage electric field.

15 In practice, the material, usually in the form of a film, has electrodes applied to both faces is placed in an oven and when at the required temperature a polarising voltage is applied across the electrodes. Typically, temperatures in the range of from 100°C - 120°C
20 are used in conjunction with voltages in the order of one megavolt per centimetre of film thickness.

The enhanced level of piezoelectricity produced in the film is a function of the magnitude of both the

treatment temperature and the applied electric field. However, the extent to which the treatment temperature can be raised is limited by the melting point of the material, whilst the extent to which the applied electric field can be increased is limited by the dielectric strength of the film. Defects in the film for example bubbles, pin holes, scratches and included foreign bodies constitute weak spots in the film and electrical breakdown of the film is liable to occur at such spots. When breakdown occurs, damage is caused to the film and to the electrodes and results sometimes in the rejection of a length of film which is thus wasted. Breakdowns are more frequent at higher applied electric fields and elevated temperatures.

Thus, although it is known that greater enhancement of piezoelectric activity is obtainable by using higher applied electric fields and elevated temperatures, it has not been possible to take full advantage of this for the reasons set out above.

According to the present invention a method of enhancing the piezoelectric properties of a polymeric material exhibiting such properties is characterised in that, before subjecting the material to a "poling" treatment, the material is exposed whilst in an atmosphere inert with respect to the material and at substantially room temperature to a quantity of gamma (γ) radiation lying within the range of from 1 Mrad to 200 Mrads (both limits included).

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Specifically, the invention also provides a method of enhancing the piezoelectric activity of polyvinylidene fluoride by exposing the latter whilst in an atmosphere inert with respect thereto and at
5 substantially room temperature to a quantity of γ radiation lying within the range of from 1 Mrad to 200 Mrads (both limits included) after which the material is subjected to a poling treatment.

The improved enhancement of the piezoelectric
10 properties of the material renders the material more useful in nearly all of its applications. For example, it improves the sensitivity of an electro-acoustic transducer fitted with a piezoelectric material according to the invention.

15 In one method embodying the invention the polyvinylidene fluoride is in the physical form of a biaxially orientated film.

The phrase "in an atmosphere inert with respect to the material", or "in an atmosphere inert with respect
20 thereto" is intended to include irradiation in a vacuum in which the air pressure does not exceed 10^{-3} mm Hg (0.13 N/m^2) as well as irradiation in an atmosphere that does not cause embrittlement of the material undergoing irradiation. It has been found that it is important to exclude oxygen
25 from the atmosphere. An example of an inert atmosphere is a nitrogen atmosphere and this can be obtained by flushing out with nitrogen the chamber in which irradiation is to be effected to remove all air.

The quantity of γ radiation to which the material is exposed preferably lies in the range of

from 1 Mrad to 99 Mrads (both limits included). The enhancement of the piezoelectric properties of the material is particularly pronounced at these lower exposure levels.

5 The invention also provides a polymeric material exhibiting piezoelectric properties which have been enhanced by a method as defined above.

 By way of example only, a method of enhancing the piezoelectric activity of biaxially orientated
10 polyvinylidene fluoride film will now be described with reference to Figure 1, the accompanying drawing, which is a schematic sectional view of a sample of the film being irradiated.

 Prior to irradiation, vacuum evaporated
15 aluminium electrodes are formed on both sides of the film using conventional techniques. Referring to Figure 1, a strip of the film 1 having, for example, a thickness of 25 μm , a width of about 30 cm and a length of a few hundred metres, is then wound onto a reel 2 and placed
20 in a dessicator 3, maintained at room temperature and exhausted to 10^{-5} mm Hg (1.3×10^{-3} N/m²), oxygen being excluded. The dessicator is in turn placed in a concrete bunker 5 and irradiated from a source of radiation 6, for example Cobalt 60. The film 1 is exposed to a preselected
25 quantity of radiation lying within the range of from 1 to 200 Mrads and illustrated schematically by arrows 4 in Figure 1; the direction and intensity of radiation incident on the film depends on the position of the dessicator 3 in the bunker. After irradiation, the
30 dessicator 3 is removed from the bunker, the reel 2 is

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removed from the dessicator and the film is poled by application across the electrodes of an electric field while the film is at an elevated temperature.

5 In the method described above, the aluminium electrodes are formed on the film before irradiation but the formation of electrodes may be deferred until after irradiation if desired.

10 Samples of films treated in various ways have been tested. In the tests the film was that produced by the firm Kureha Kagaku Kogyo Kabushiki Kaisha of Tokyo, Japan and is of 25 μm thickness. Prior to treatment vacuum evaporated aluminium electrodes were formed on both sides of the film using conventional techniques.

15 The sample was then placed in a vacuum chamber maintained at room temperature and exhausted to 10^{-5} mm Hg (1.3×10^{-3} N/m²), oxygen being excluded. The chamber was then removed to a source of γ radiation, namely Cobalt 60. After irradiation, the sample was removed. Subsequently, the sample was "poled" by application across the electrodes
20 of an electric field while the sample was at an elevated temperature.

After poling the sample was subjected to tests to measure its piezoelectric activity. The activity was measured by stressing the sample in a direction lying
25 along the machine or roll direction of the film.

The following table shows the piezoelectric activity of the film. The first column of the table sets out the irradiation treatment to which the portion of film was exposed, whilst the second column gives details of the
30 "poling" treatment. Of the details given in the second column, the first figure is the poling field, the second is the poling temperature and the third is the duration of the poling treatment. The third column gives the measured value of the piezoelectric coefficient for stress applied along the machine direction.

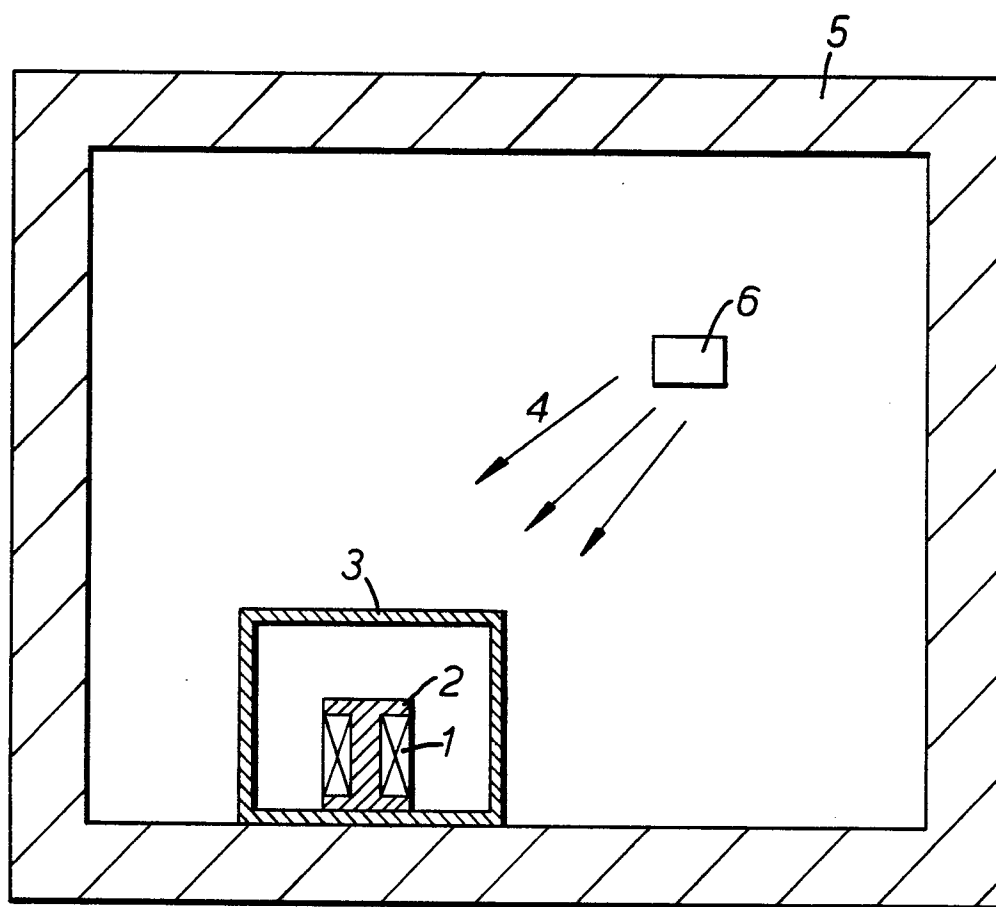
Irradiation Treatment	Poling Treatment	Piezoelectric voltage coefficient <u>g_{31} (Vm/N)</u>
None	None	1.8×10^{-5}
None	0.5 MV/cm, 100°C, 45 min.	1.4×10^{-2}
200 Mrad	0.25 MV/cm, 100°C, 45 min.	1.2×10^{-2}
53 Mrad	0.5 MV/cm, 100°C, 45 min.	3.4×10^{-2}
99 Mrad	0.5 MV/cm, 100°C, 45 min.	2.9×10^{-2}
None	1.0 MV/cm, 100°C, 45 min.	3.8×10^{-2}
12 Mrad	1.0 MV/cm 100°C, 45 min.	5.8×10^{-2}
25 Mrad	1.0 MV/cm 100°C, 45 min.	6.1×10^{-2}
53 Mrad	1.0 MV/cm, 100°C, 45 min.	6.1×10^{-2}
99 Mrad	1.0 MV/cm, 100°C, 45 min.	3.6×10^{-2}

The treated material is suitable for use in microphone transmitters, receivers and pressure transducers.

Claims:

1. A method of enhancing the piezoelectric properties of a polymeric material (1) exhibiting such properties, the method including the step of subjecting the material to a "poling" treatment, characterised in that, before the "poling" treatment, the material (1) is exposed whilst in an atmosphere inert with respect to the material and at substantially room temperature to a quantity of γ radiation (4) lying within the range of from 1 Mrad to 200 Mrads (both limits included).
2. A method as claimed in claim 1, further characterised in that the material (1) is polyvinylidene fluoride.
3. A method as claimed in claim 2, further characterised in that the polyvinylidene fluoride is in the form of a biaxially orientated film.
4. A method as claimed in any preceding claim, further characterised in that the inert atmosphere is a vacuum in which the air pressure does not exceed 10^{-3} mm Hg (0.13 N/m^2).
5. A method as claimed in any preceding claim, further characterised in that the quantity of γ radiation (4) to which the material (1) is exposed lies in the range of from 1 Mrad to 99 Mrads (both limits included).
6. A polymeric material exhibiting piezoelectric properties characterised in that the piezoelectric properties of the material (4) have been enhanced by a method as claimed in any preceding claim.

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*FIG. 1.*



DOCUMENTS CONSIDERED TO BE RELEVANT			CLASSIFICATION OF THE APPLICATION (Int. Cl. ²)
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	
A	CHEMICAL ABSTRACTS, vol. 83, no. 6, 11 augustus 1975 Columbus Ohio USA HASEGAWA YO et al. "Vacuum treatment of electrets to stabilize their surface change", page 590, 1st column, abstract no. 52 017 U. * Complete * ---	1	H 01 L 41/22
A	FR - A - 2 108 561 (KUREHA) * Claim 1 * ---	1	TECHNICAL FIELDS SEARCHED (Int.Cl. ²)
A	FR - A - 2 031 247 (WESTERN ELECTRIC COMPANY) * Claim 1 * -----	1	H 01 L 41/22 H 01 G 7/02
			CATEGORY OF CITED DOCUMENTS
			X: particularly relevant A: technological background O: non-written disclosure P: intermediate document T: theory or principle underlying the invention E: conflicting application D: document cited in the application L: citation for other reasons
			&: member of the same patent family, corresponding document
The present search report has been drawn up for all claims			
Place of search	Date of completion of the search	Examiner	
The Hague	11-09-1978	PELSERS	